BC846BDW1T1G, BC847BDW1T1G, BC848CDW1T1G

Dual General Purpose Transistors

NPN Duals

These transistors are designed for general purpose amplifier applications. They are housed in the SOT−363/SC−88 which is designed for low power surface mount applications.

Features

- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	BC846	BC847	BC848	Unit
Collector − Emitter Voltage	V_{CEO}	65	45	30	V
Collector − Base Voltage	V_{CBO}	80	50	30	V
Emitter − Base Voltage	V_{EBO}	6.0	6.0	5.0	V
Collector Current − Continuous	I_C	100	100	100	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

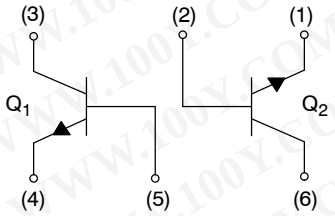
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation Per Device FR−5 Board (Note 1) T_A = 25°C	P_D	380 250	mW
Derate Above 25°C		3.0	mW/°C
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	328	°C/W
Junction and Storage Temperature Range	T_J, T_{stg}	−55 to +150	°C

1. FR−5 = 1.0 x 0.75 x 0.062 in

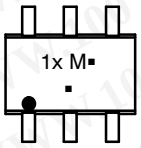
ON Semiconductor®

http://onsemi.com



SOT−363
CASE 419B
STYLE 1

MARKING DIAGRAM



1x = Specific Device Code
x = B, F, G, L
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I_C = 10 mA)	BC846 Series	$V_{(BR)CEO}$	65	–	–	V
	BC847 Series		45	–	–	
	BC848 Series		30	–	–	
Collector – Emitter Breakdown Voltage (I_C = 10 μA, V_{EB} = 0)	BC846 Series	$V_{(BR)CES}$	80	–	–	V
	BC847 Series		50	–	–	
	BC848 Series		30	–	–	
Collector – Base Breakdown Voltage (I_C = 10 μA)	BC846 Series	$V_{(BR)CBO}$	80	–	–	V
	BC847 Series		50	–	–	
	BC848 Series		30	–	–	
Emitter – Base Breakdown Voltage (I_E = 1.0 μA)	BC846 Series	$V_{(BR)EBO}$	6.0	–	–	V
	BC847 Series		6.0	–	–	
	BC848 Series		5.0	–	–	
Collector Cutoff Current (V_{CB} = 30 V)		I_{CBO}	–	–	15	nA
(V_{CB} = 30 V, T_A = 150°C)			–	–	5.0	μA
ON CHARACTERISTICS						
DC Current Gain (I_C = 10 μA, V_{CE} = 5.0 V)	BC846B, BC847B,	h_{FE}	–	150	–	–
	BC847C, BC848C		–	270	–	
(I_C = 2.0 mA, V_{CE} = 5.0 V)	BC846B, BC847B,		200	290	450	
	BC847C, BC848C		420	520	800	
Collector – Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA)		$V_{CE(sat)}$	–	–	0.25	V
(I_C = 100 mA, I_B = 5.0 mA)			–	–	0.6	
Base – Emitter Saturation Voltage (I_C = 10 mA, I_B = 0.5 mA)		$V_{BE(sat)}$	–	0.7	–	V
(I_C = 100 mA, I_B = 5.0 mA)			–	0.9	–	
Base – Emitter Voltage (I_C = 2.0 mA, V_{CE} = 5.0 V)		$V_{BE(on)}$	580	660	700	mV
(I_C = 10 mA, V_{CE} = 5.0 V)			–	–	770	
SMALL–SIGNAL CHARACTERISTICS						
Current – Gain – Bandwidth Product (I_C = 10 mA, V_{CE} = 5.0 Vdc, f = 100 MHz)		f_T	100	–	–	MHz
Output Capacitance (V_{CB} = 10 V, f = 1.0 MHz)		C_{obo}	–	–	4.5	pF
Noise Figure (I_C = 0.2 mA, V_{CE} = 5.0 Vdc, R_S = 2.0 kΩ,f = 1.0 kHz, BW = 200 Hz)		NF	–	–	10	dB

TYPICAL CHARACTERISTICS – BC846BDW1T1G

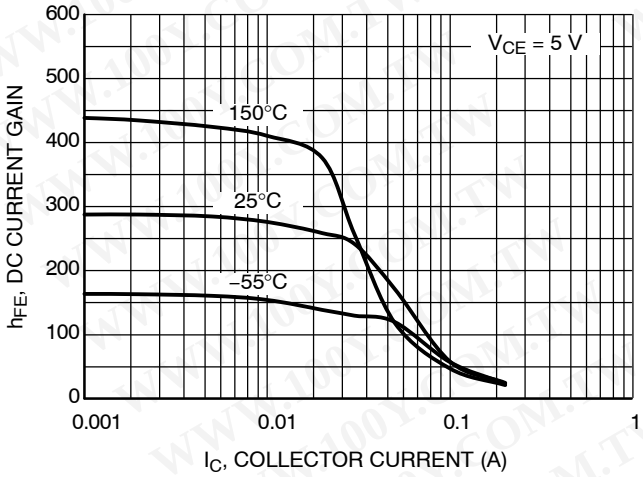


Figure 1. DC Current Gain at V_{CE} = 5 V

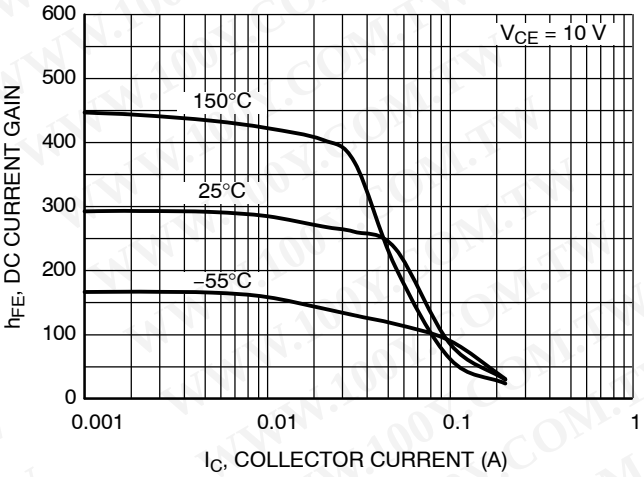


Figure 2. DC Current Gain at V_{CE} = 10 V

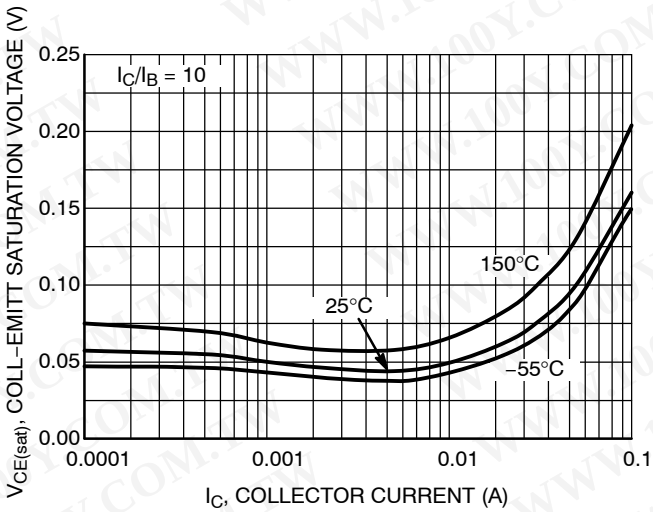


Figure 3. $V_{CE(sat)}$ at I_C/I_B = 10

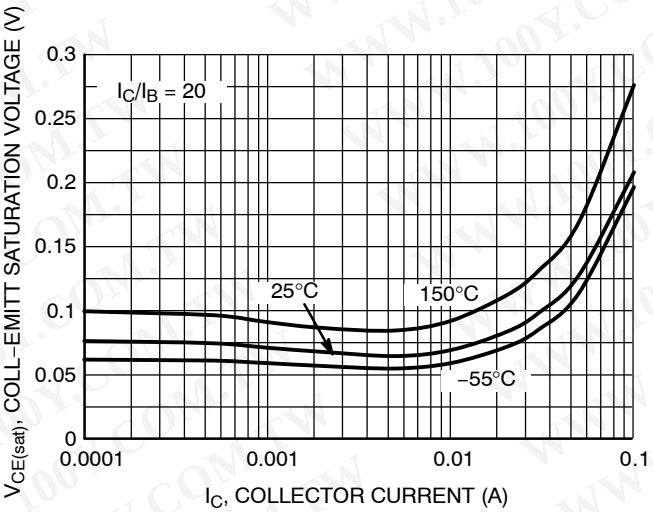


Figure 4. $V_{CE(sat)}$ at I_C/I_B = 20

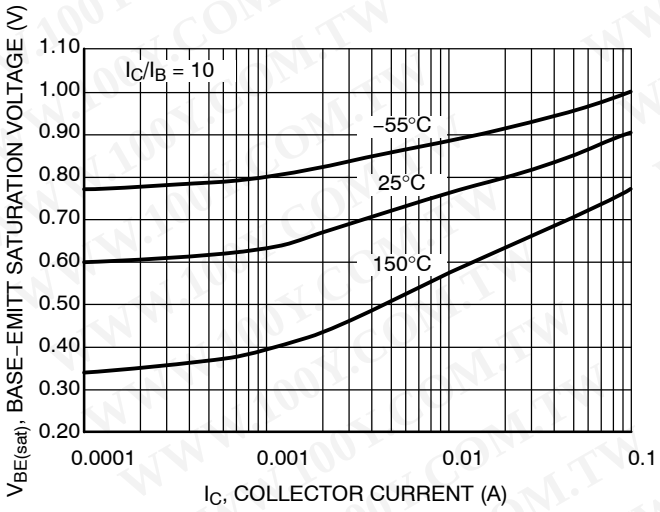


Figure 5. $V_{BE(sat)}$ at I_C/I_B = 10

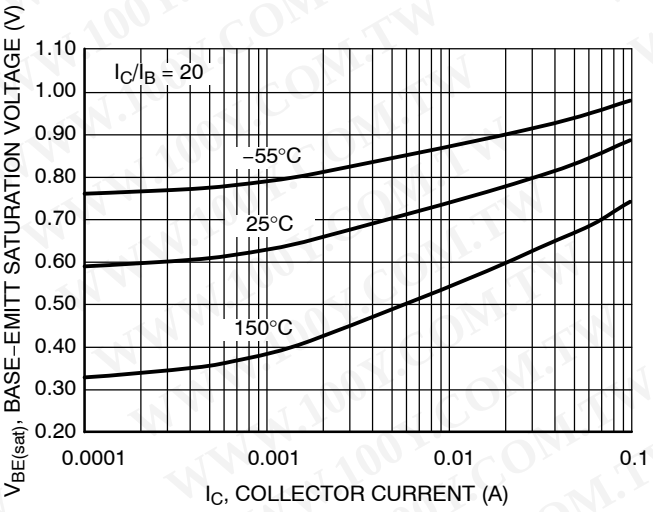


Figure 6. $V_{BE(sat)}$ at I_C/I_B = 20

TYPICAL CHARACTERISTICS – BC846BDW1T1G

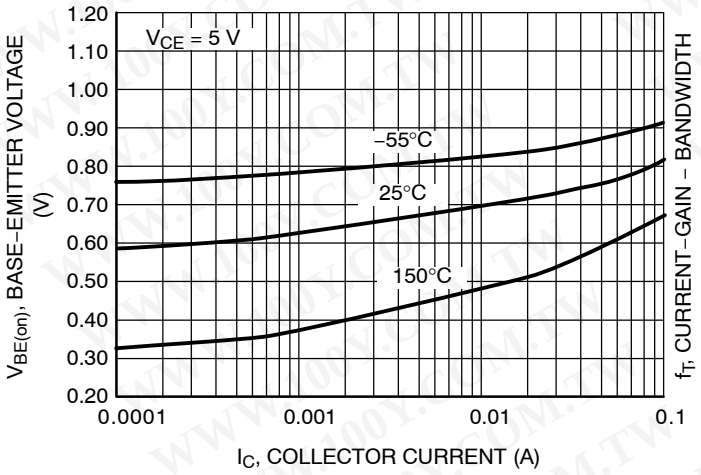


Figure 7. $V_{BE(on)}$ at V_{CE} = 5 V

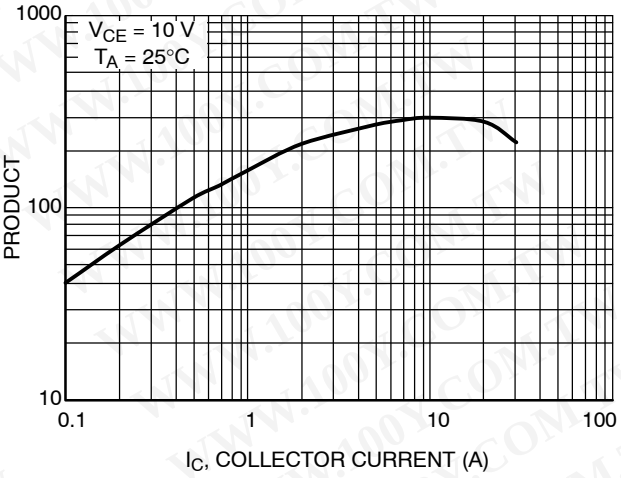


Figure 8. Current – Gain – Bandwidth Product

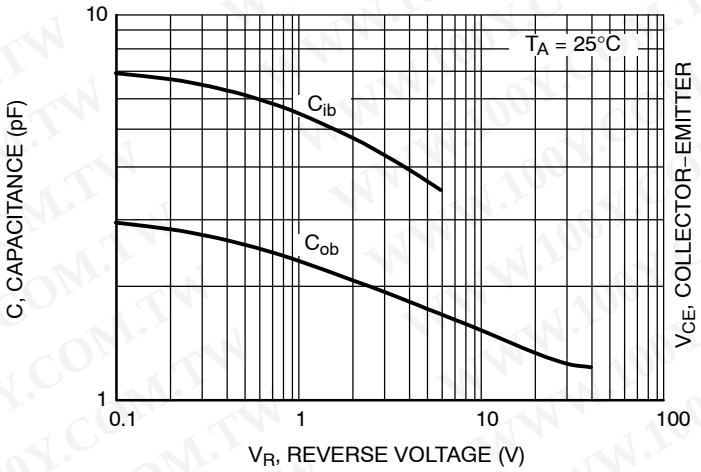


Figure 9. Capacitances

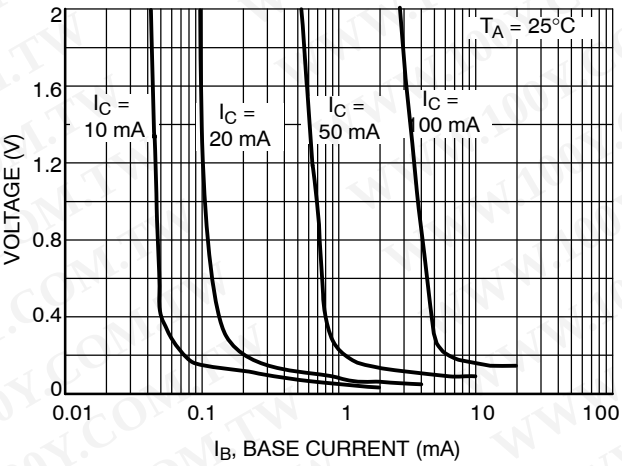


Figure 10. Collector Saturation Region

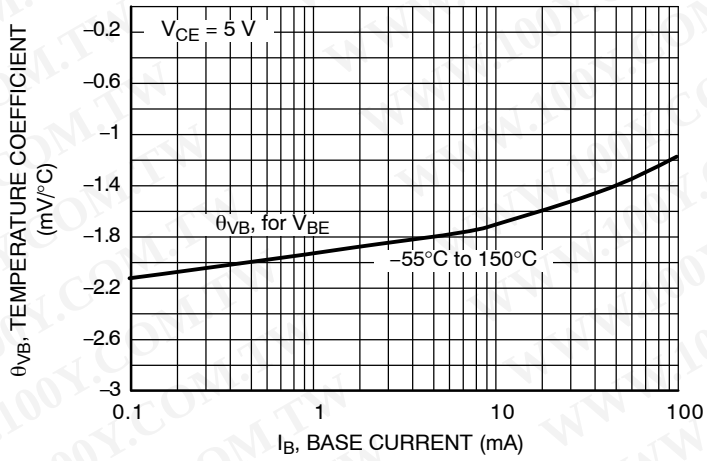


Figure 11. Base−Emitter Temperature Coefficient

TYPICAL CHARACTERISTICS – BC847BDW1T1G

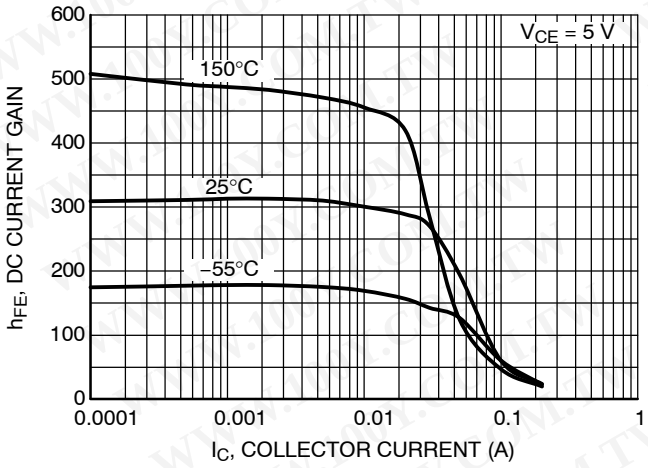


Figure 12. DC Current Gain at V_{CE} = 5 V

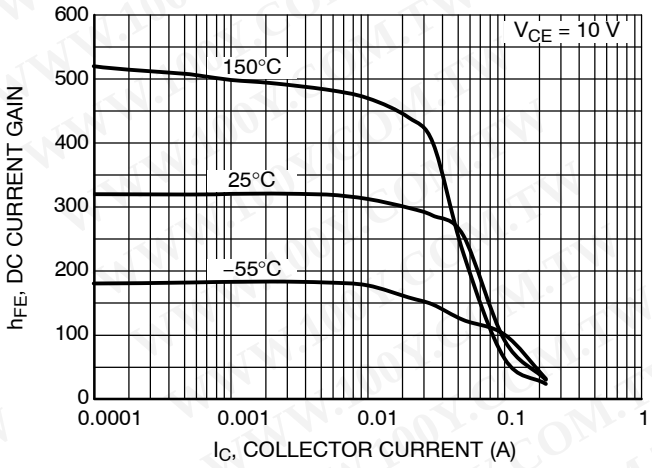


Figure 13. DC Current Gain at V_{CE} = 10 V

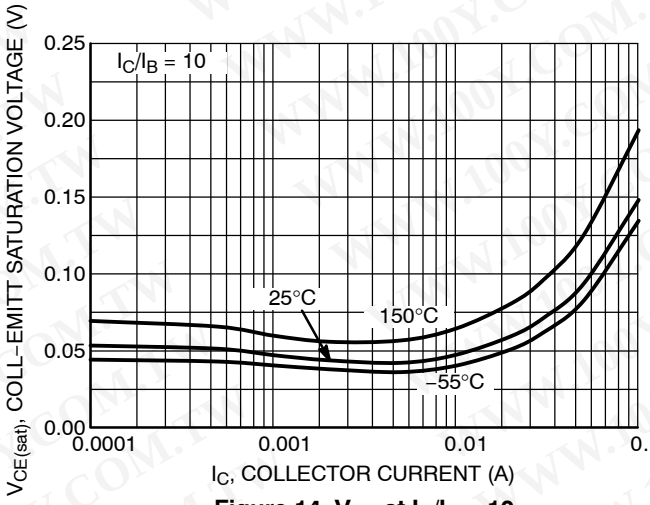


Figure 14. V_{CE} at I_C/I_B = 10

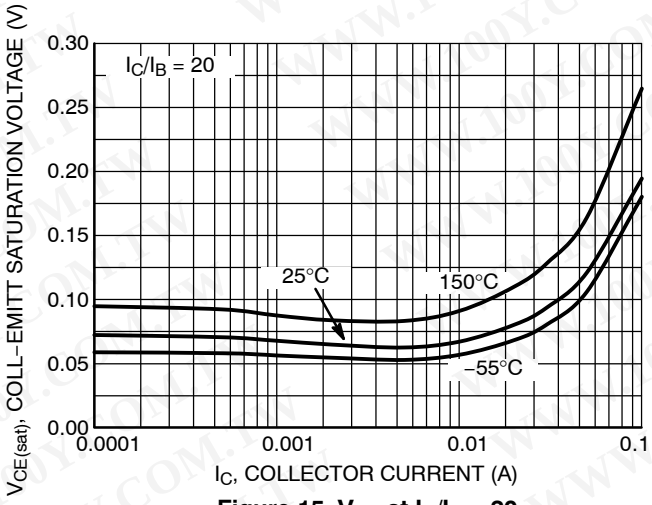


Figure 15. V_{CE} at I_C/I_B = 20

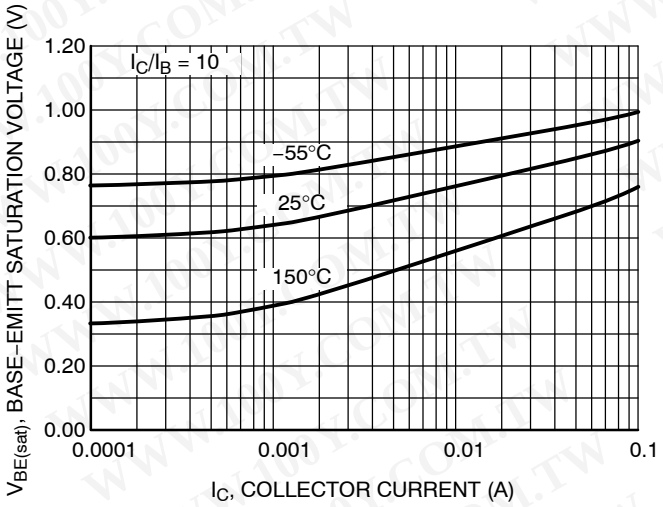


Figure 16. $V_{BE(sat)}$ at I_C/I_B = 10

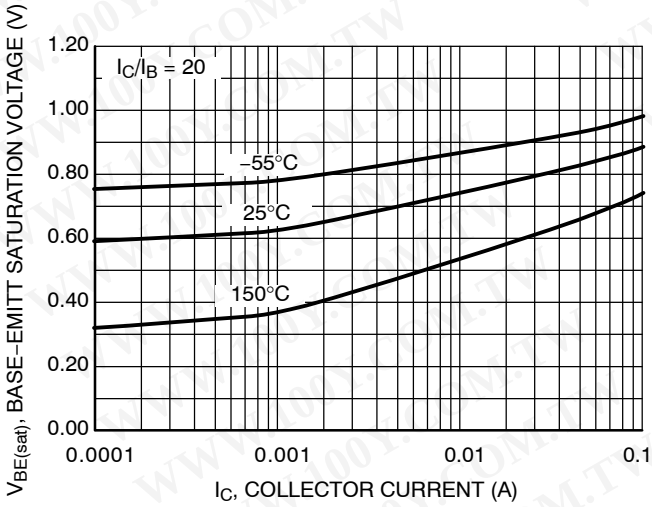


Figure 17. $V_{BE(sat)}$ at I_C/I_B = 20

TYPICAL CHARACTERISTICS – BC847BDW1T1G

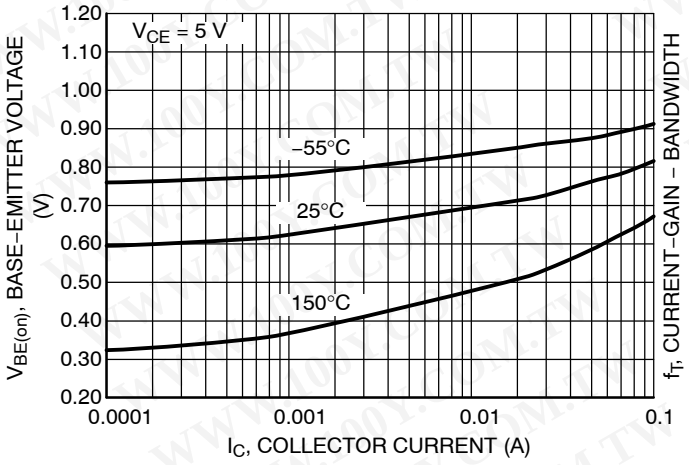


Figure 18. $V_{BE(on)}$ at V_{CE} = 5 V

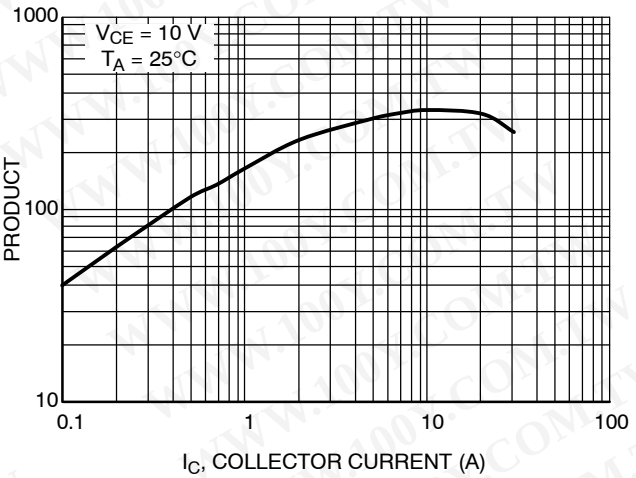


Figure 19. Current – Gain – Bandwidth Product

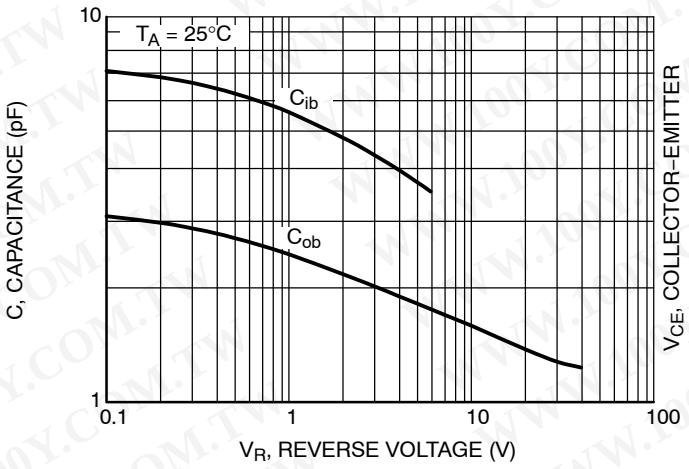


Figure 20. Capacitances

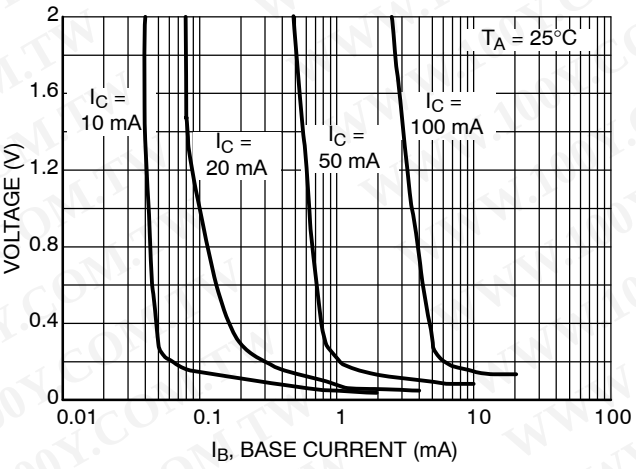


Figure 21. Collector Saturation Region

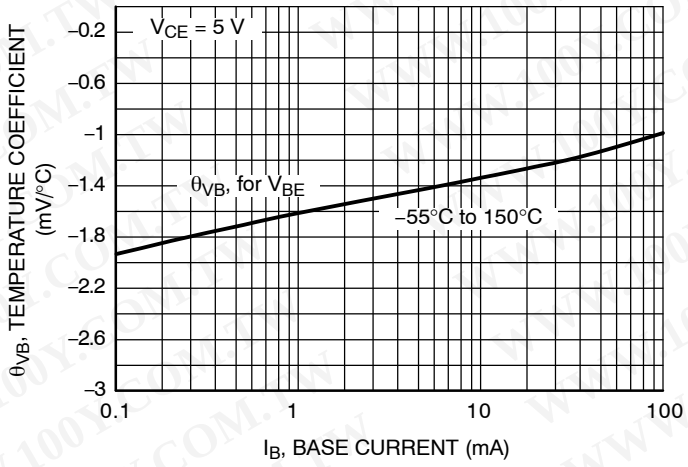


Figure 22. Base–Emitter Temperature Coefficient

TYPICAL CHARACTERISTICS – BC848CDW1T1G

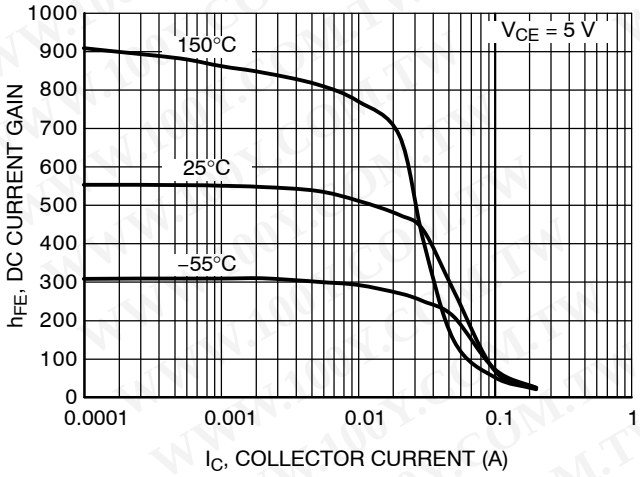


Figure 23. DC Current Gain at V_{CE} = 5 V

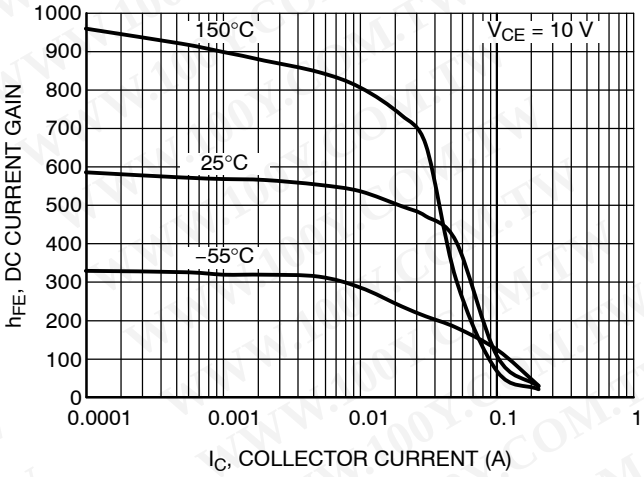


Figure 24. DC Current Gain at V_{CE} = 10 V

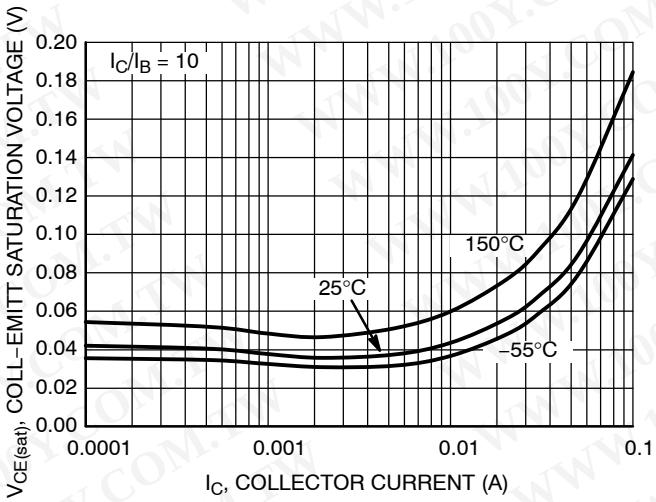


Figure 25. V_{CE} at I_C/I_B = 10

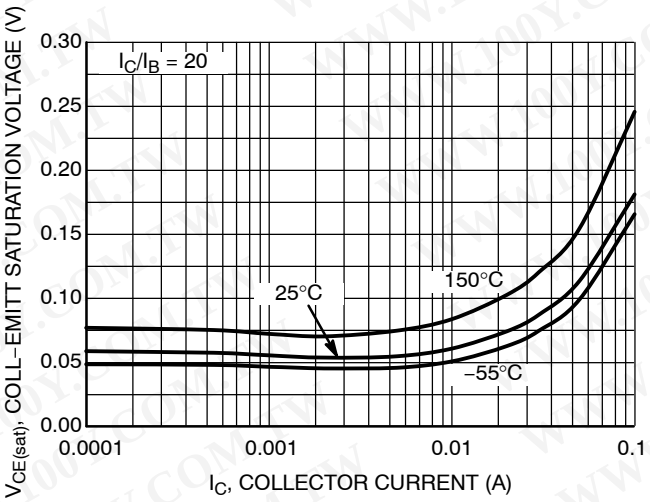


Figure 26. V_{CE} at I_C/I_B = 20

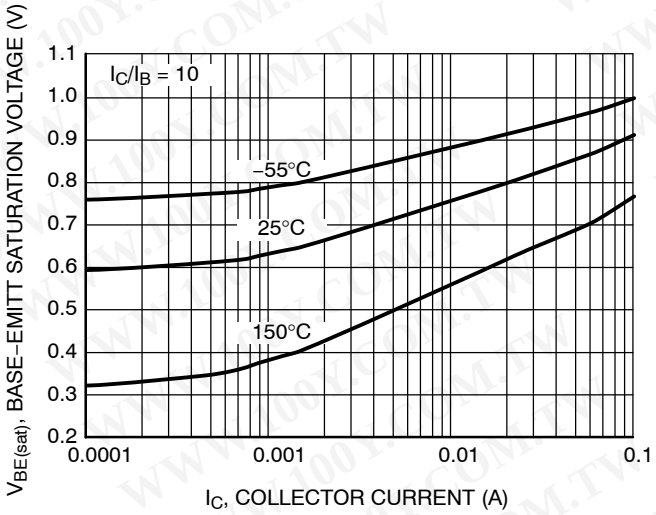


Figure 27. $V_{BE(sat)}$ at I_C/I_B = 10

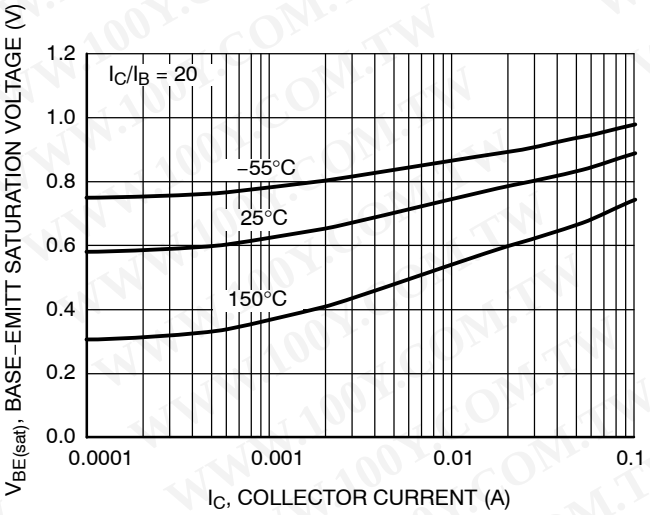


Figure 28. $V_{BE(sat)}$ at I_C/I_B = 20

TYPICAL CHARACTERISTICS – BC848CDW1T1G

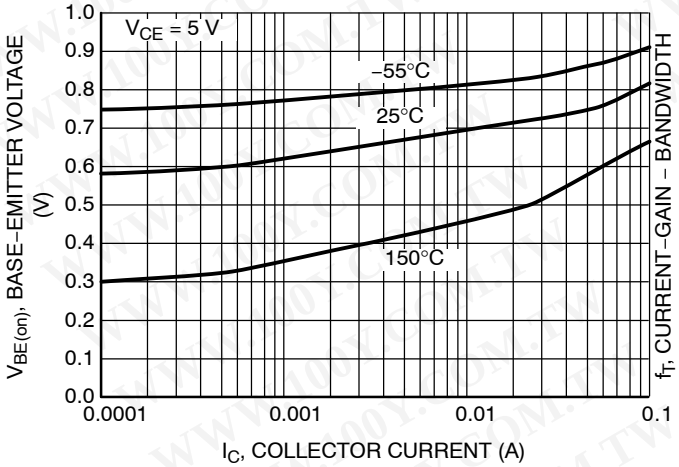


Figure 29. $V_{BE(on)}$ at V_{CE} = 5 V

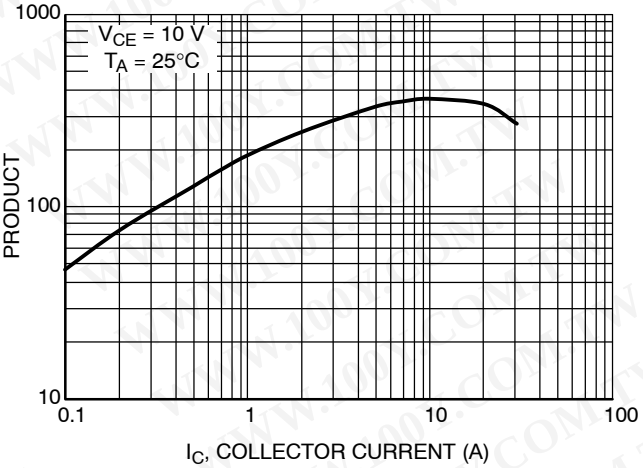


Figure 30. Current – Gain – Bandwidth Product

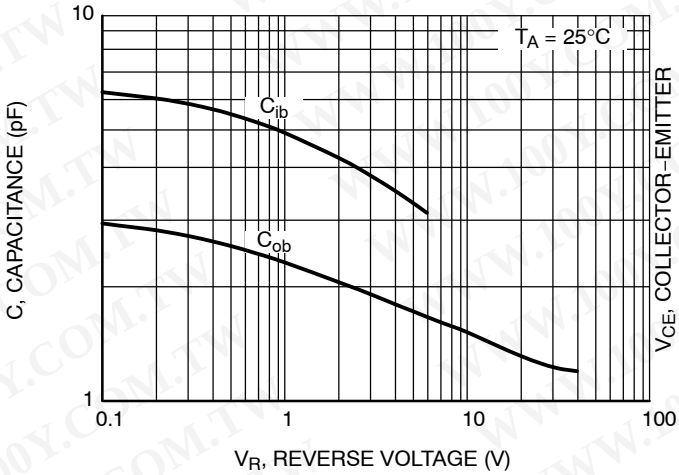


Figure 31. Capacitances

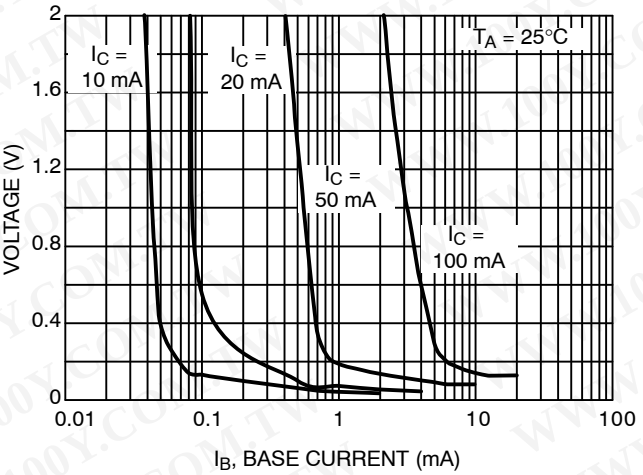


Figure 32. Collector Saturation Region

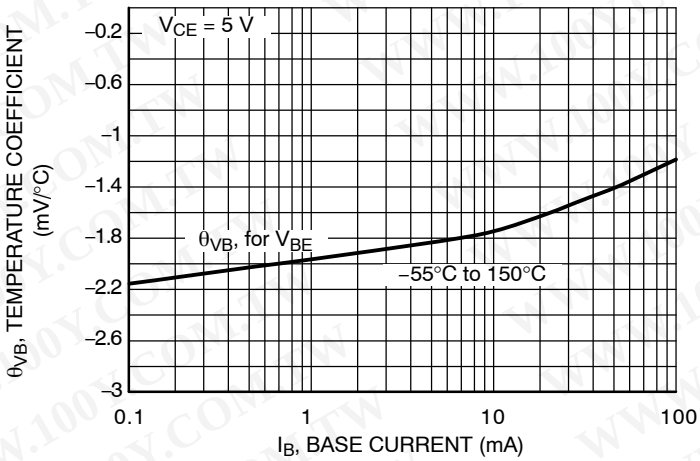


Figure 33. Base−Emitter Temperature Coefficient

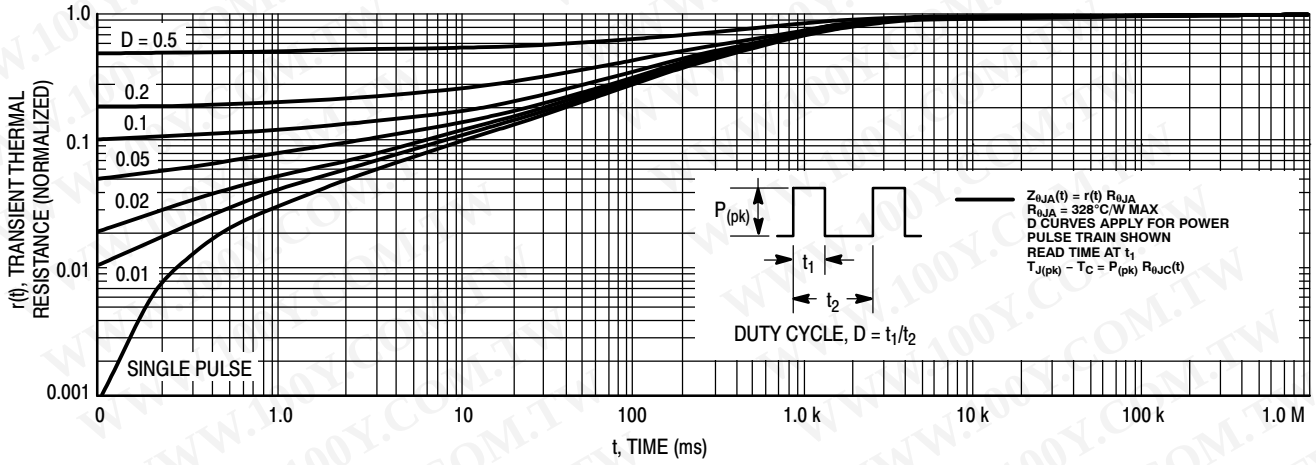


Figure 34. Thermal Response

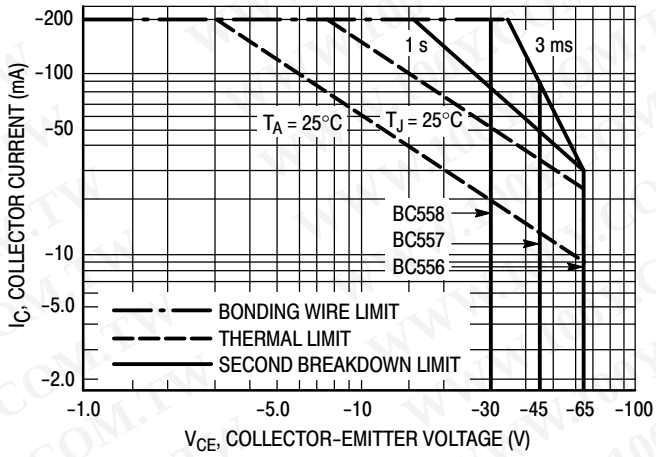


Figure 35. Active Region Safe Operating Area

The safe operating area curves indicate I_C–V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 35 is based upon $T_{J(pk)}$ = 150°C; T_C or T_A is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq$ 150°C. $T_{J(pk)}$ may be calculated from the data in Figure 34. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

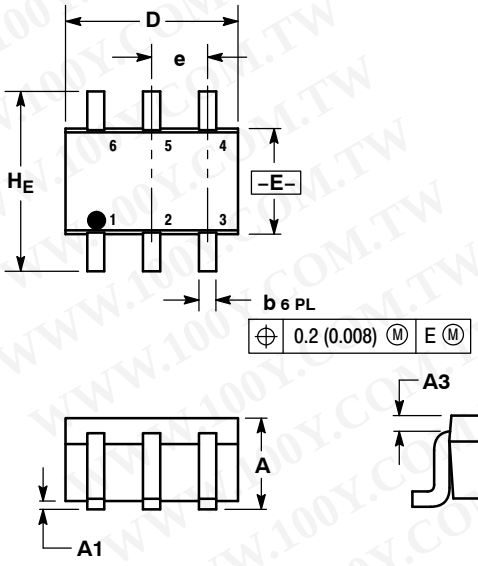
ORDERING INFORMATION

Device	Markings	Package	Shipping†
BC846BDW1T1G	1B	SOT−363 (Pb−Free)	3000 / Tape & Reel
BC847BDW1T1G	1F	SOT−363 (Pb−Free)	3000 / Tape & Reel
BC847BDW1T3G	1F	SOT−363 (Pb−Free)	10000 / Tape & Reel
BC847CDW1T1G	1G	SOT−363 (Pb−Free)	3000 / Tape & Reel
BC848CDW1T1G	1L	SOT−363 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

SC−88 (SC70−6/SOT−363)
CASE 419B−02
ISSUE W

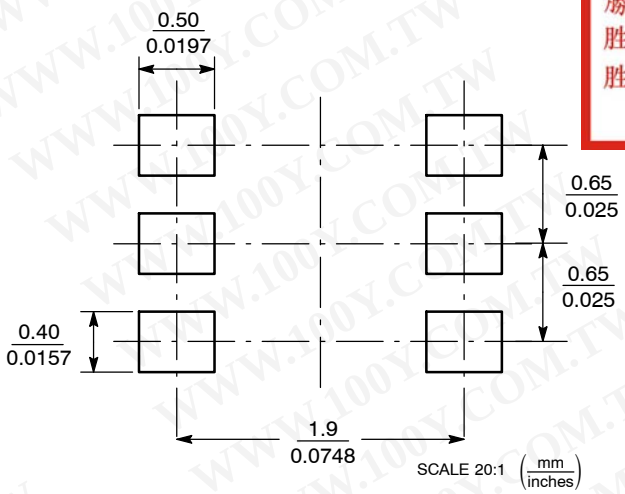


NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419B−01 OBSOLETE, NEW STANDARD 419B−02.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.20 REF			0.008 REF		
b	0.10	0.21	0.30	0.004	0.008	0.012
C	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
H_E	2.00	2.10	2.20	0.078	0.082	0.086

STYLE 1:
PIN 1. EMITTER 2
2. BASE 2
3. COLLECTOR 1
4. EMITTER 1
5. BASE 1
6. COLLECTOR 2

SOLDERING FOOTPRINT*



*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
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